



SBR1U40LP

1.0A SBR[®] SUPER BARRIER RECTIFIER

Features

- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- Lead Free By Design, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Notes 2 & 3)

Mechanical Data

- Case: X1-DFN1411-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Lead Frame. Solderable per MIL-STD-202, Method 208
- Weight: 2.35mg (approximate)

X1-DFN1411-3



Top View



Bottom View

_ 2
3

Top View Internal Schematic

Ordering Information (Note 4)

Dort Number	Casa	Deckering
Part Number	Case	Packaging
SBR1U40LP-7	X1-DFN1411-3	3000/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. No purposely added lead. Halogen and Antimony free.

2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.

4. For packaging details, go to our website at http://www.diodes.com

Marking Information



 $\underline{D}4$ = Product Type Marking Code YM = Date Code Marking Y = Year (ex: U = 2007) M = Month (ex: 9 = September)

Date Code Key

Year	2007	20	08	2009	2010	20	11	2012	2013	20	14	2015
Code	U	١	/	W	Х	Ň	(Z	А	E	3	С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage (Note 5) Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	40	V
RMS Reverse Voltage	V _{R(RMS)}	28	V
Average Rectified Output Current (See Figure 1)	Io	1.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	5	А
Non-Repetitive Peak Forward Surge Current 15s Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	2.6	А

Thermal Characteristics

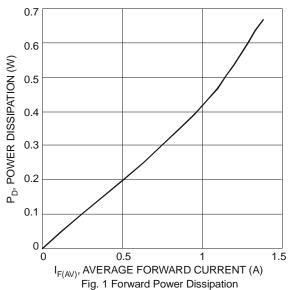
Characteristic	Symbol	Value	Unit
Power Dissipation	PD	400	mW
Maximum Thermal Resistance Junction to Ambient (Note 6)	$R_{ heta JA}$	190	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
		-	0.39	0.42		I _F = 0.5A, T _J = 25°C
Forward Valtage Drop	VF	-	0.46	0.49	V	$I_F = 1.0A, T_J = 25^{\circ}C$
Forward Voltage Drop		-	0.34	0.37		I _F = 0.5A, T _J = 125°C
		-	0.43	0.47		I _F = 1.0A, T _J = 125°C
Leakage Current (Note 7)	1-	-	-	50	μΑ	$V_R = 40V, T_J = 25^{\circ}C$
Leakage Current (Note 7)	IR	-	-	100	mA	V _R = 40V, T _J = 125°C

Notes:

 $\begin{array}{l} 5. \ V_{\text{RRM}} \ characteristic is base on 1mA leakage current test condition \\ 6. \ Device mounted on Polymide substrate 1" x 1", 2oz. Copper double sided PCB board. \\ 7. \ Short \ duration \ pulse test \ used to minimize \ self-heating effect. \end{array}$



I_F, INSTANTANEOUS FORWARD CURRENT (A) $T_A = 25^{\circ}C$ 0.001 $T_{\Delta} = -55^{\circ}C$ 0.0001 0.1 0.2 0.3 0.5 0.4 0 V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics

0.1 T_A

0.01

= 150°C Τ_A

 $T_A = 85^{\circ}C$

= 125°C

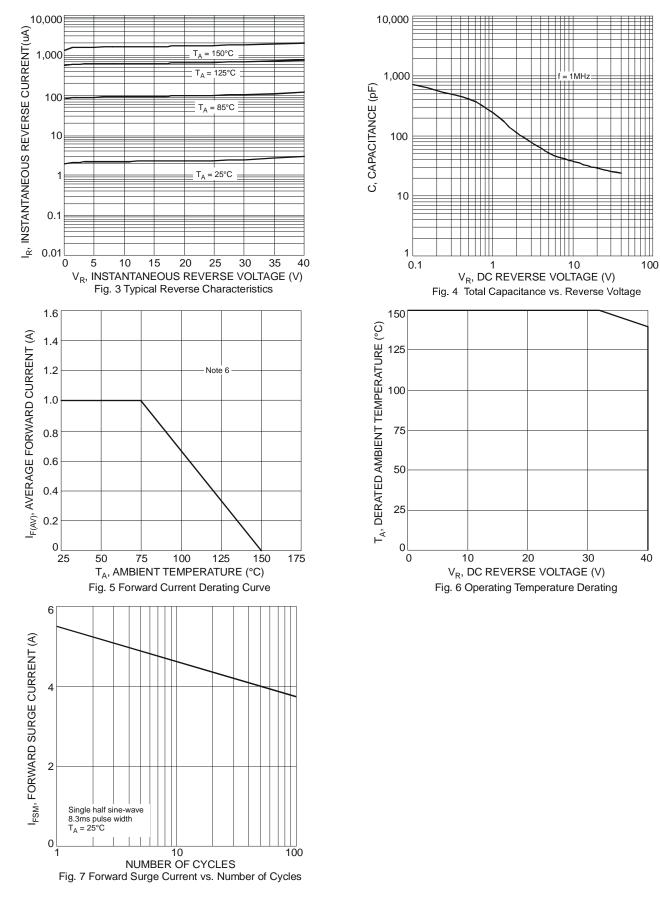
0.8

0.6

0.7



SBR1U40LP

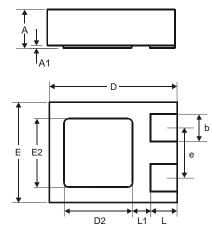


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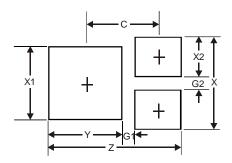


Package Outline Dimensions



X1-DFN1411-3					
Dim	Min	Max	Тур		
Α	0.47	0.53	0.50		
A1	0	0.05	0.02		
b	0.25	0.35	0.30		
D	1.35	1.475	1.40		
D2	0.65	0.85	0.75		
Е	1.05	1.175	1.10		
E2	0.65	0.85	0.75		
e			0.55		
L	0.225	0.325	0.275		
L1			0.20		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.38
G1	0.15
G2	0.15
Х	0.95
X1	0.75
X2	0.40
Ŷ	0.75
С	0.76



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